

CMOS 8-Input NOR/OR Gate

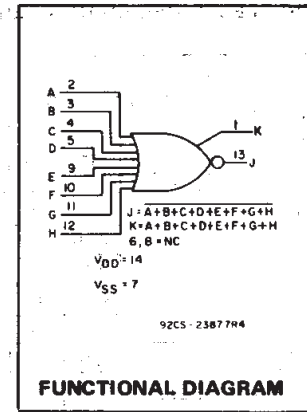
High-Voltage Types (20-Volt Rating)

■ CD4078B NOR/OR Gate provides the system designer with direct implementation of the positive-logic 8-input NOR and OR functions and supplements the existing family of CMOS gates.

The CD4078B types are supplied in 14-lead dual-in-line ceramic packages (D and F suffixes), 14-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).

Features:

- Medium-Speed Operation:
 $t_{PHL}, t_{PLH} = 75 \text{ ns (typ.) at } V_{DD} = 10 \text{ V}$
- Buffered inputs and output
- 5-V, 10-V, and 15-V parametric ratings
- Standardized symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of $1 \mu\text{A}$ at 18 V over full package-temperature range:
 $100 \text{ nA at } 18 \text{ V and } 25^\circ\text{C}$
- Noise margin (over full package-temperature range):
 $1 \text{ V at } V_{DD} = 5 \text{ V}$
 $2 \text{ V at } V_{DD} = 10 \text{ V}$ $2.5 \text{ V at } V_{DD} = 15 \text{ V}$
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{DD})	-0.5V to +20V
Voltages referenced to V_{SS} Terminal	
INPUT VOLTAGE RANGE, ALL INPUTS	-0.5V to $V_{DD} + 0.5\text{V}$
DC INPUT CURRENT, ANY ONE INPUT	$\pm 10\text{mA}$
POWER DISSIPATION PER PACKAGE (P_D):	
For $T_A = -55^\circ\text{C}$ to $+100^\circ\text{C}$	500mW
For $T_A = +100^\circ\text{C}$ to $+125^\circ\text{C}$	Derate Linearly at $12\text{mW}/^\circ\text{C}$ to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR $T_A = \text{FULL PACKAGE-TEMPERATURE RANGE (All Package Types)}$	100mW
OPERATING-TEMPERATURE RANGE (T_A)	-55°C to $+125^\circ\text{C}$
STORAGE TEMPERATURE RANGE (T_{stg})	-65°C to $+150^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance $1/16 \pm 1/32$ inch ($1.59 \pm 0.79\text{mm}$) from case for 10s max	$+285^\circ\text{C}$

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	Min.	Max.	Units
Supply Voltage Range (For T_A Full Package Temperature Range)	3	18	V

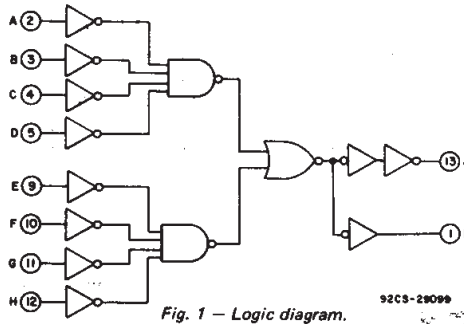


Fig. 1 - Logic diagram.

DYNAMIC ELECTRICAL CHARACTERISTICS

At $T_A = 25^\circ\text{C}$; Input $t_r, t_f = 20 \text{ ns}$, $C_L = 50 \text{ pF}$, $R_L = 200\text{k}\Omega$

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS	
		V_{DD} VOLTS	TYP.		MAX.
Propagation Delay Time, t_{PHL}, t_{PLH}		5	150	300	ns
		10	75	150	
		15	55	110	
Transition Time, t_{THL}, t_{TLH}		5	100	200	ns
		10	50	100	
		15	40	80	
Input Capacitance, C_{IN}	Any Input	5	7.5	pF	

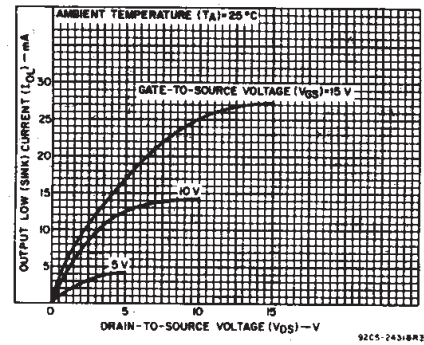


Fig. 2 - Typical output low (sink) current characteristics.

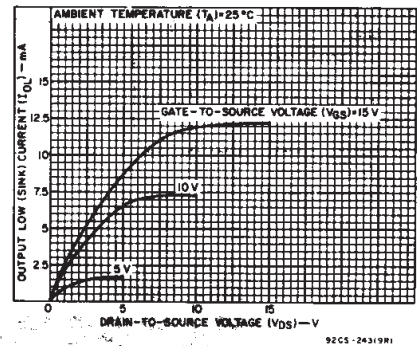


Fig. 3 - Minimum output low (sink) current characteristics.

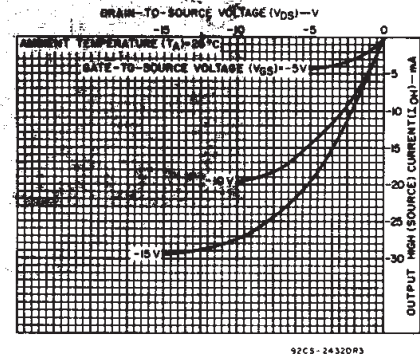


Fig. 4 - Typical output high (source) current characteristics.

CD4078B Types

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V _O (V)	V _{IN} (V)	V _{DD} (V)	-55	-40	+85	+125	+25			
								Min.	Typ.	Max.	
Quiescent Device Current, I _{DD} Max.	-	0.5	5	0.25	0.25	7.5	7.5	-	0.01	0.25	μA
	-	0.10	10	0.5	0.5	15	15	-	0.01	0.5	
	-	0.15	15	1	1	30	30	-	0.01	1	
	-	0.20	20	5	5	150	150	-	0.02	5	
Output Low (Sink) Current, I _{OL} Min.	0.4	0.5	5	0.64	0.61	0.42	0.36	0.51	1	mA	
	0.5	0.10	10	1.6	1.5	1.1	0.9	1.3	2.6		
	1.5	0.15	15	4.2	4	2.8	2.4	3.4	6.8		
Output High (Source) Current, I _{OH} Min.	4.6	0.5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	mA	
	2.5	0.5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2		
	9.5	0.10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6		
	13.5	0.15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8		
Output Voltage: Low Level, V _{OL} Max.	-	0.5	5	0.05				0	0.05	V	
	-	0.10	10	0.05				0	0.05		
	-	0.15	15	0.05				0	0.05		
Output Voltage: High Level, V _{OH} Min.	-	0.5	5	4.95				4.95	5	V	
	-	0.10	10	9.95				9.95	10		
	-	0.15	15	14.95				14.95	15		
Input Low Voltage, V _{IL} Max.	0.5, 4.5	-	5	1.5				-	-	1.5	V
	1.9	-	10	3				-	-	3	
	1.5, 13.5	-	15	4				-	-	4	
Input High Voltage, V _{IH} Min.	0.5, 4.5	-	5	3.5				3.5	-	-	V
	1.9	-	10	7				7	-	-	
	1.5, 13.5	-	15	11				11	-	-	
Input Current I _{IN} Max.		0.18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μA

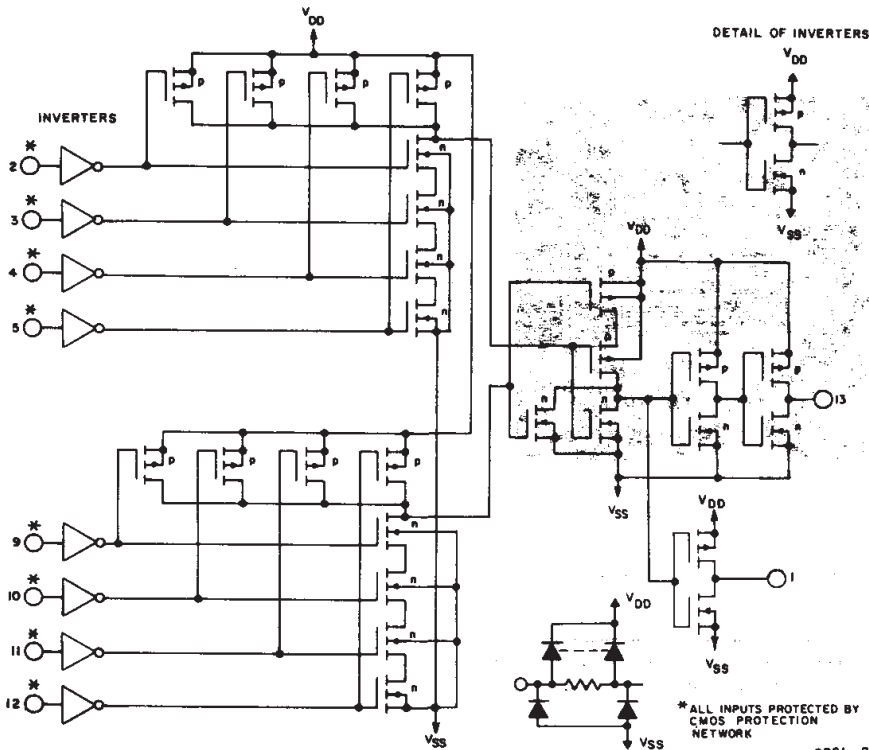
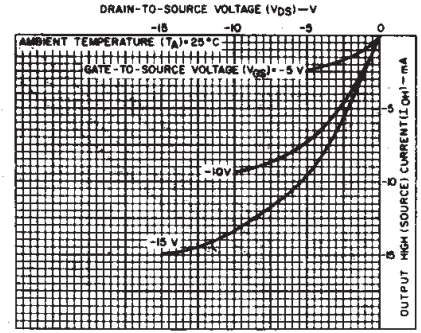


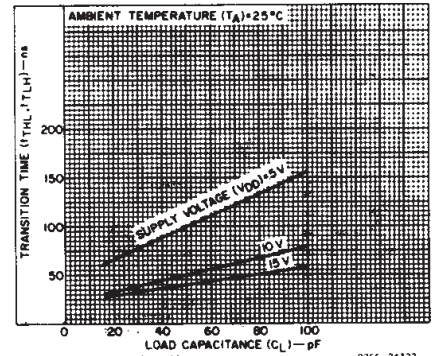
Fig. 8 - Schematic diagram.

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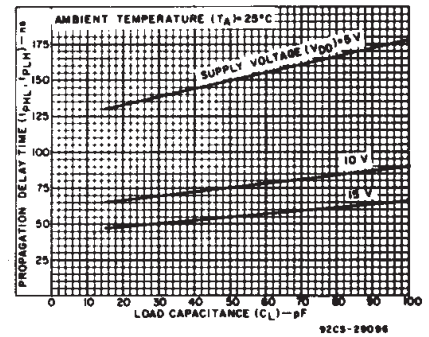
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Fig. 5 - Minimum output high (source) current characteristics.



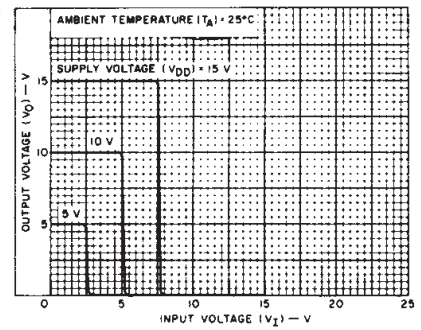
92CS-24322

Fig. 6 - Typical transition time as a function of load capacitance.



92CS-29096

Fig. 7 - Typical propagation delay time as a function of load capacitance.



92CS-28904

Fig. 9 - Typical voltage transfer characteristics (NOR output).

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COMMERCIAL CMOS
HIGH VOLTAGE ICs

CD4078B Types

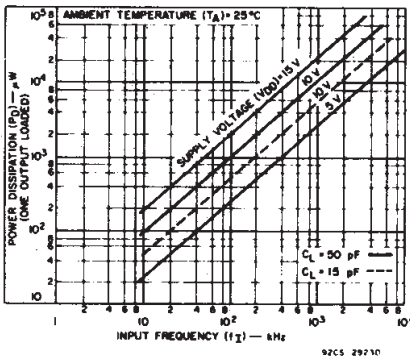


Fig. 10 – Typical dynamic power dissipation as a function of frequency.

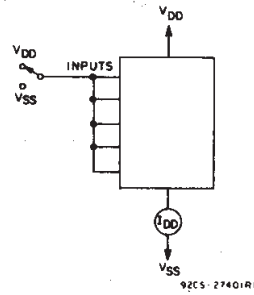


Fig. 11 – Quiescent-device-current test circuit.

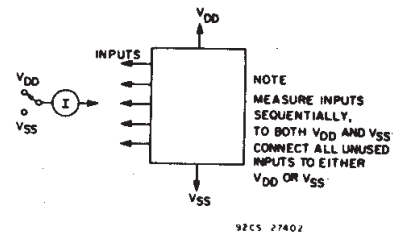


Fig. 12 – Input current test circuit.

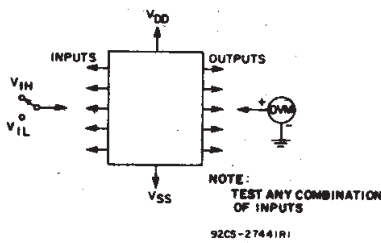


Fig. 13 – Input-voltage test circuit.

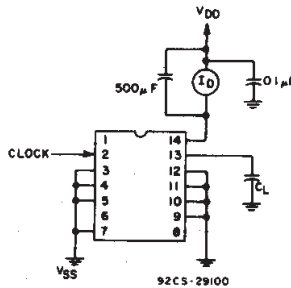
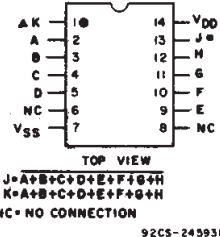
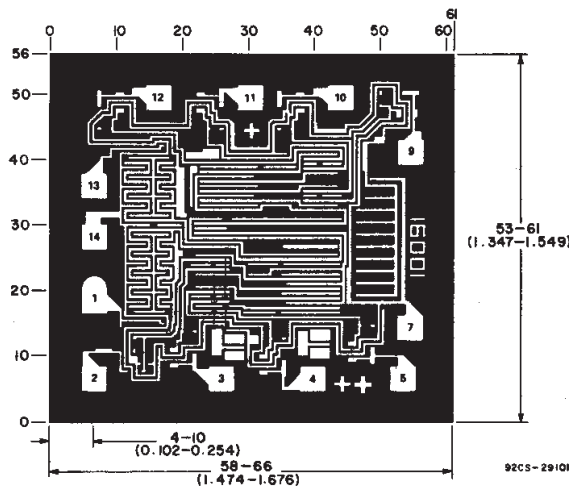


Fig. 14 – Dynamic power dissipation test circuit.



TERMINAL ASSIGNMENT



Dimensions and pad layout for CD4078BH.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

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